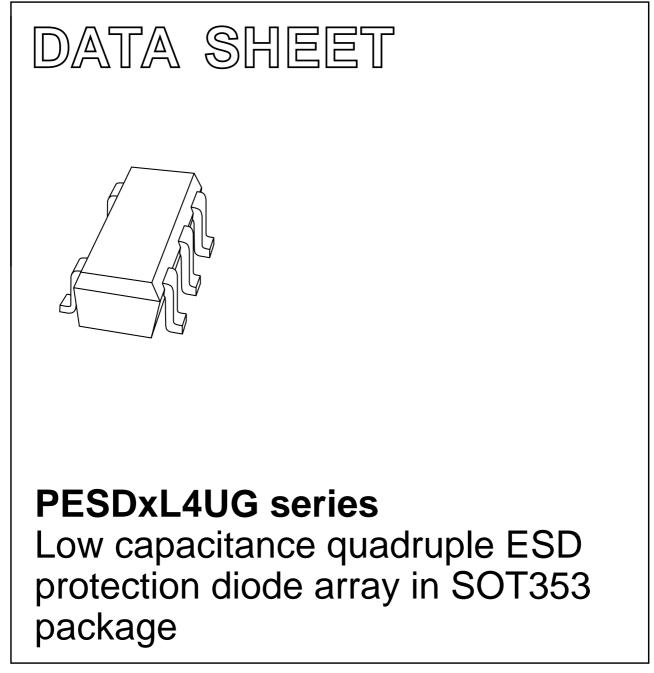
## DISCRETE SEMICONDUCTORS



Product specification

2004 Mar 23



### **PESDxL4UG** series

#### FEATURES

- Uni-directional ESD protection of up to four lines
- Low diode capacitance
- Maximum peak pulse power:  $P_{pp} = 30$  W at  $t_p = 8/20\mu s$
- Low clamping voltage: V<sub>CL(R)</sub> = 12 V at I<sub>pp</sub> = 3 A
- Ultra low leakage current:  $I_{RM} = 5 \text{ nA}$  at  $V_{RWM} = 5 \text{ V}$
- ESD protection > 20 kV
- IEC 61000-4-2; level 4 (ESD).

#### APPLICATIONS

- · Cellular handsets and accessories
- Portable electronics
- Computers and peripherals
- Communications systems
- Audio and video equipment.

#### DESCRIPTION

ESD protection diode arrays designed to protect up to four transmissions or data lines from ElectroStatic Discharge (ESD) damage and other transients.

#### MARKING

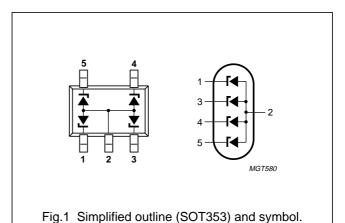
TYPE NUMBER	MARKING
PESD3V3L4UG	L1
PESD5V0L4UG	L2

#### QUICK REFERENCE DATA

SYMBOL	PARAMETER	VALUE	UNIT
V <sub>RWM</sub>	reverse standoff voltage		
	PESD3V3L4UG	3.3	V
	PESD5V0L4UG	5	V
C <sub>d</sub>	diode capacitance		
	PESD3V3L4UG	22	pF
	PESD5V0L4UG	16	pF
	number of protected lines	4	

#### PINNING

PIN	DESCRIPTION	
1	cathode 1	
2	common anode	
3	cathode 2	
4	cathode 3	
5	cathode 4	



#### ORDERING INFORMATION

		PACKAGE	
ITFE NUMBER	TYPE NUMBER NAME DESCRIPTION		VERSION
PESD3V3L4UG	UG – plastic surface mounted package; 5 leads		SOT353
PESD5V0L4UG	—	plastic surface mounted package; 5 leads	SOT353

### PESDxL4UG series

#### LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT		
Per diode	Per diode						
I <sub>pp</sub>	peak pulse current	8/20 μs; notes 1 and 2					
	PESD3V3L4UG		-	3	A		
	PESD5V0L4UG		_	2.5	A		
P <sub>pp</sub>	peak pulse power	8/20 μs; notes 1 and 2	-	30	W		
I <sub>FSM</sub>	non-repetitive peak forward current	$t_p = 1 \text{ ms}; \text{ square pulse}$ – 3.5		3.5	A		
I <sub>ZSM</sub>	non-repetitive peak reverse current	t <sub>p</sub> = 1 ms; square pulse					
	PESD3V3L4UG		-	0.9	A		
	PESD5V0L4UG		_	0.8	A		
P <sub>tot</sub>	total power dissipation $T_{amb} = 25 \text{ °C}; \text{ note } 3$		-	300	mW		
P <sub>ZSM</sub>	$_{SM}$ non-repetitive peak reverse power $t_p = 1$ ms; square pulse; see Fig.4 – dissipation		6	W			
T <sub>stg</sub>	storage temperature		-65	+150	°C		
Tj	junction temperature		-	150	°C		
T <sub>amb</sub>	operating ambient temperature		-65	+150	°C		

#### Notes

- 1. Non-repetitive current pulse 8/20 µs exponentially decaying waveform; see Fig.5.
- 2. Between any of pins 1, 3, 4 or 5 and pin 2.
- 3. Device mounted on standard printed-circuit board.

#### ESD maximum ratings

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
Per diode				
ESD	electrostatic discharge capability	IEC 61000-4-2 (contact discharge); notes 1 and 2	20	kV
		HBM MIL-Std 883	10	kV

#### Notes

- 1. Device stressed with ten non-repetitive Electrostatic Discharge (ESD) pulses.
- 2. Measured from any of pins 1, 3, 4, or 5 to pin 2.

#### ESD standards compliance

STANDARD	CONDITION
IEC 61000-4-2, level 4 (ESD)	>15 kV (air); >8 kV (contact)
HBM MIL-Std 883, class 3	>4 kV

### **PESDxL4UG** series

#### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient	all diodes loaded	410	K/W
R <sub>th(j-s)</sub>	thermal resistance from junction to solder point	one diode loaded; note 1	200	K/W
		all diodes loaded; note 1	185	K/W

#### Note

1. Solder point of common anode (pin 2).

#### **ELECTRICAL CHARACTERISTICS**

 $T_i = 25 \ ^{\circ}C$  unless otherwise specified.

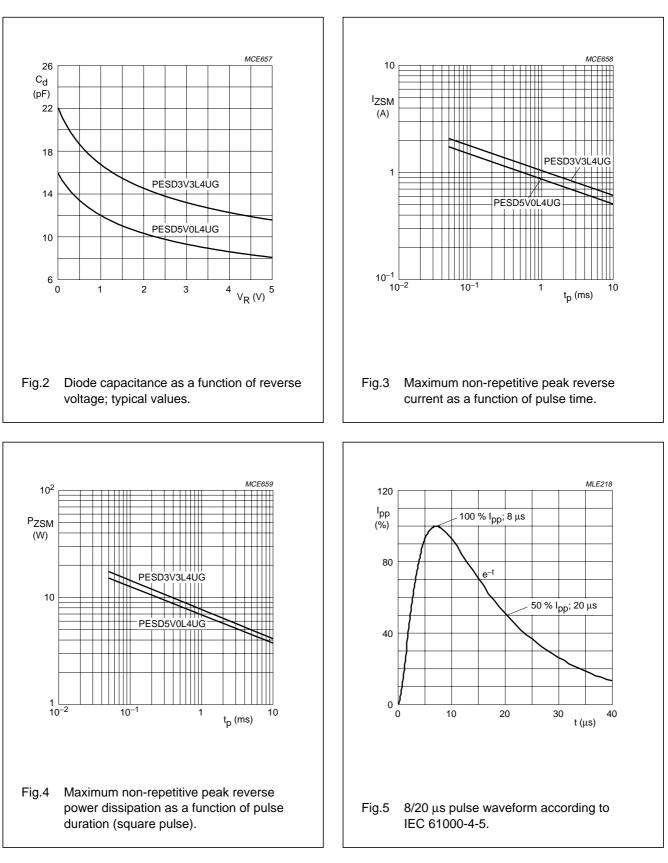
SYMBOL	PARAMETER CONDITIONS			TYP.	MAX.	UNIT
Per diode		·	•	•	•	·
V <sub>F</sub>	forward voltage	I <sub>F</sub> = 200 mA	_	1	1.2	V
I <sub>RM</sub>	reverse leakage current					
	PESD3V3L4UG	V <sub>RWM</sub> = 3.3 V	_	75	300	nA
	PESD5V0L4UG	V <sub>RWM</sub> = 5 V	_	5	25	nA
V <sub>CL(R)</sub>	clamping voltage					
	PESD3V3L4UG	$I_{pp} = 1 \text{ A}$ ; notes 1 and 2	_	_	8	V
		$I_{pp} = 3 \text{ A}$ ; notes 1 and 2	_	_	12	V
	PESD5V0L4UG	I <sub>pp</sub> = 1 A; notes 1 and 2	_	-	10	V
		$I_{pp} = 2.5 \text{ A}$ ; notes 1 and 2	_	_	13	V
V <sub>RWM</sub>	reverse stand-off voltage					
	PESD3V3L4UG		_	_	3.3	V
	PESD5V0L4UG		_	_	5	V
V <sub>BR</sub>	breakdown voltage	I <sub>Z</sub> = 1 mA				
	PESD3V3L4UG		5.32	5.6	5.88	V
	PESD5V0L4UG		6.46	6.8	7.14	V
r <sub>diff</sub>	differential resistance	I <sub>R</sub> = 1 mA				
	PESD3V3L4UG		_	_	200	Ω
	PESD5V0L4UG		_	_	100	Ω
C <sub>d</sub>	diode capacitance					
	PESD3V3L4UG	V <sub>R</sub> = 0 V; f = 1 MHz	_	22	28	pF
		V <sub>R</sub> = 5 V; f = 1 MHz	_	12	17	pF
	PESD5V0L4UG	V <sub>R</sub> = 0 V; f = 1 MHz	_	16	19	pF
		V <sub>R</sub> = 5 V; f = 1 MHz	_	8	11	pF

#### Notes

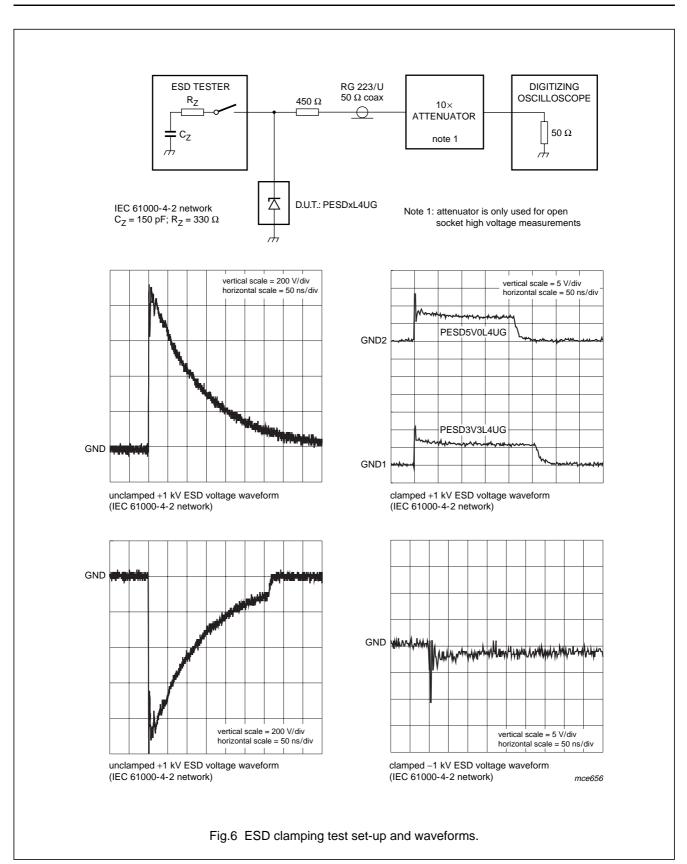
1. Non-repetitive current pulse  $8 \times 20$  ms exponentially decay waveform; see Fig.5.

2. Between any of pins 1, 3, 4 or 5 and pin 2.

### **PESDxL4UG** series

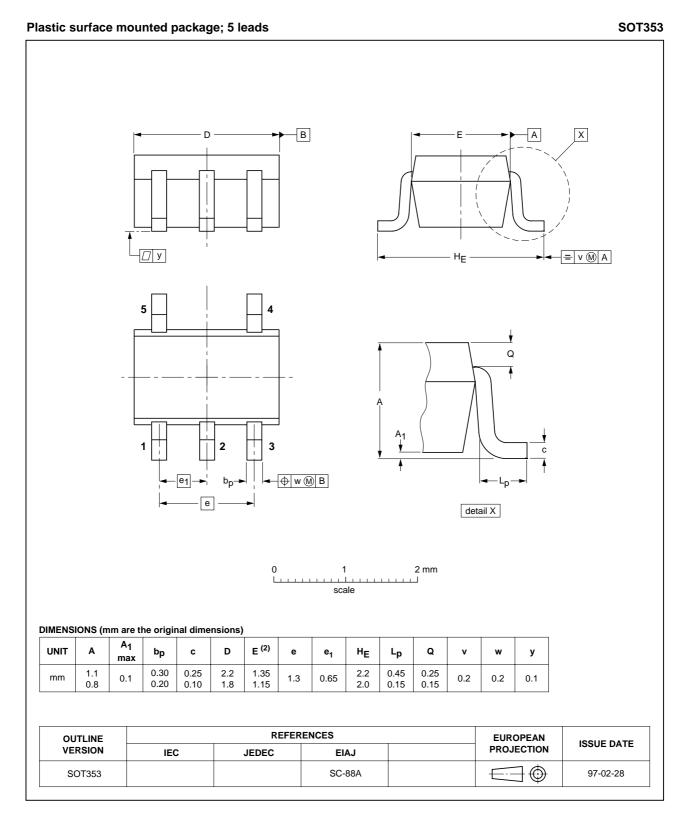


### **PESDxL4UG** series



### **PESDxL4UG** series

#### PACKAGE OUTLINE



### PESDxL4UG series

#### DATA SHEET STATUS

LEVEL	DATA SHEET STATUS <sup>(1)</sup>	PRODUCT STATUS <sup>(2)(3)</sup>	DEFINITION
I	Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
11	Preliminary data	Qualification	This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in order to improve the design and supply the best possible product.
	Product data	Production	This data sheet contains data from the product specification. Philips Semiconductors reserves the right to make changes at any time in order to improve the design, manufacturing and supply. Relevant changes will be communicated via a Customer Product/Process Change Notification (CPCN).

#### Notes

- 1. Please consult the most recently issued data sheet before initiating or completing a design.
- 2. The product status of the device(s) described in this data sheet may have changed since this data sheet was published. The latest information is available on the Internet at URL http://www.semiconductors.philips.com.
- 3. For data sheets describing multiple type numbers, the highest-level product status determines the data sheet status.

#### DEFINITIONS

**Short-form specification** — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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#### **Contact information**

For additional information please visit http://www.semiconductors.philips.com. Fax: +31 40 27 24825 For sales offices addresses send e-mail to: sales.addresses@www.semiconductors.philips.com.

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